

Transmissive Sensor

- Choice of phototransistor or photodarlington output
- Accurate position sensing
- 0.070 in.(1.78 mm) slot width
- 18.0 in.(457 mm) min. 22 AWG UL 1007 wire leads



The HOA1870 series consists of an infrared emitting diode facing an NPN silicon phototransistor (HOA1870- 031) or photodarlington (HOA1870- 033) encased in a black thermoplastic housing. Detector switching takes place whenever an opaque object passes through the slot between emitter and detector. A minimum of 18.0 in.(457 mm) lead wires provides alternate electrical connection when PC board mounting is not possible. This device is ideal for use in applications in which maximum position resolution is desired. Both emitter and detector have a 0.006 in.(0.152 mm) x 0.040 in.(1.02 mm) vertical aperture. The HOA1870 series employs plastic molded components. For additional component information see SEP8506, SDP8406 and SDP8106.

Housing material is polycarbonate. Housings are soluble in chlorinated hydrocarbons and ketones. Recommended cleaning agents are methanol and isopropanol.

Orange - IRED Anode
White - Detector Collector
Green - IRED Cathode
Blue - Detector Emitter

Tolerance	3 plc decimals	±0.010(0.25)
	2 plc decimals	±0.020(0.51)



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ELECTRICAL CHARACTERISTICS (25°C unless otherwise noted)

PARAMETER	SYMBOL	MIN	TYP	MAX	UNITS	TEST CONDITIONS
IR EMITTER						
Forward Voltage	V_F			1.6	V	$I_F=20\text{ mA}$
Reverse Leakage Current	I_R			10	μA	$V_R=3\text{ V}$
DETECTOR						
Collector-Emitter Breakdown Voltage	$V_{(BR)CEO}$				V	$I_C=100\text{ }\mu\text{A}$
HOA1870-031		30				
HOA1870-033		15				
Emitter-Collector Breakdown Voltage	$V_{(BR)ECO}$	5.0			V	$I_E=100\text{ }\mu\text{A}$
Collector Dark Current	I_{CEO}			100	nA	$V_{CE}=10\text{ V}$ $I_F=0$
HOA1870-031				250		
HOA1870-033						
COUPLED CHARACTERISTICS						
On-State Collector Current	$I_{C(ON)}$				mA	$V_{CE}=5\text{ V}$ $I_F=20\text{ mA}$
HOA1870-031		0.3				
HOA1870-033		2.0				
Collector-Emitter Saturation Voltage	$V_{CE(SAT)}$			0.4	V	$I_F=20\text{ mA}$ $I_C=40\text{ }\mu\text{A}$ $I_C=250\text{ }\mu\text{A}$
HOA1870-031				1.1		
HOA1870-033						
Rise And Fall Time	t_r, t_f		15		μs	$V_{CC}=5\text{ V}, I_C=1\text{ mA}$ $R_L=1000\text{ }\Omega$ $R_L=100\text{ }\Omega$
HOA1870-031			75			
HOA1870-033						

ABSOLUTE MAXIMUM RATINGS

(25°C Free-Air Temperature unless otherwise noted)

Operating Temperature Range	-40°C to 85°C
Storage Temperature Range	-40°C to 85°C
Soldering Temperature (5 sec)	240°C

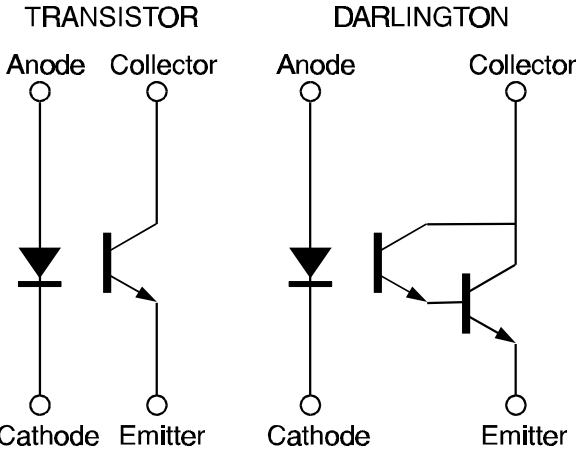
IR EMITTER

Power Dissipation	100 mW ⁽¹⁾
Reverse Voltage	3 V
Continuous Forward Current	50 mA

DETECTOR

	TRANS.	DARLINGTON
Collector-Emitter Voltage	30 V	15 V
Emitter-Collector Voltage	5 V	5 V
Power Dissipation	100 mW ⁽¹⁾	100 mW ⁽¹⁾
Collector DC Current	30 mA	30 mA

SCHEMATIC



Honeywell reserves the right to make changes in order to improve design and supply the best products possible.

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Fig. 1 IRED Forward Bias Characteristics

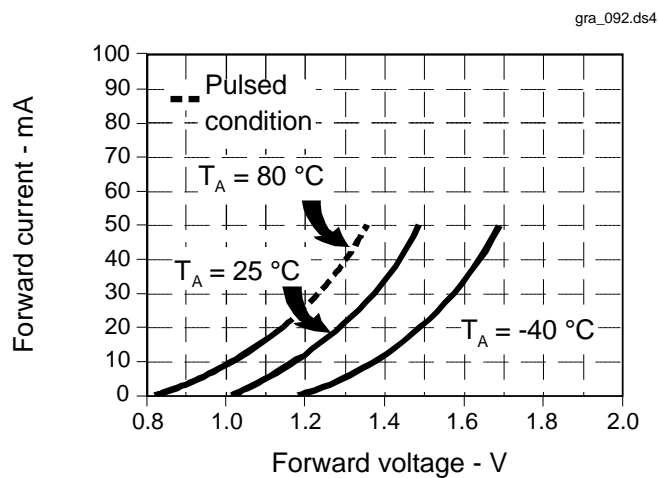


Fig. 2 Non-Saturated Switching Time vs Load Resistance

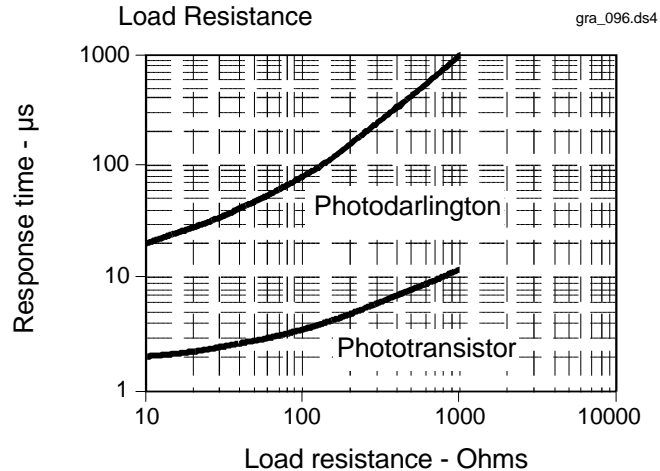


Fig. 3 Dark Current vs Temperature

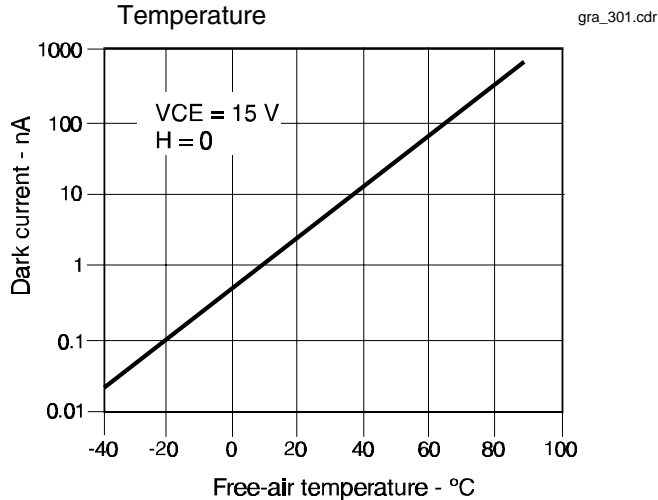
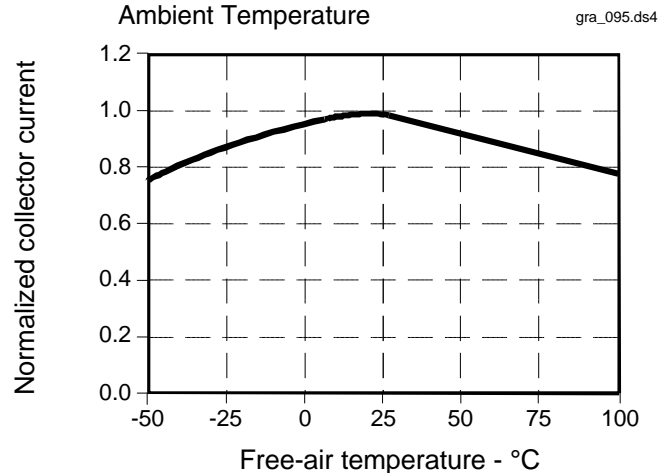


Fig. 4 Collector Current vs Ambient Temperature



All Performance Curves Show Typical Values

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